Unit C3, Broadoak Business Park Ashburton Road West Trafford Park, Manchester M17 1RW, UK

Tel: +44 161 873 7334 Email: info@icsld.com

ICS PINARY25G1-20GSG

25Gbps 1260/1620nm Top Illuminated MESA InGaAs PIN Diode

PRODUCT DESCRIPTION:

The PINARY25G1-20GSG is a top illuminated MESA InGaAs PIN diode array chip in GSG configuration with 100 µm pitch. The device has a 20µm aperture with 250µm device pitch. The device is optimised for single mode fibre at wavelength ranges from 1260nm to 1620nm for optical receiver applications with data rates up to 25Gbps. The device features extremely low capacitance and low dark currents and a large bandwidth at low reverse bias.

The chip pad metallisation layout is optimized for easy wire-bonding to most common TIAs.

Electrical and Optical Characteristics (temperature = 25°C):

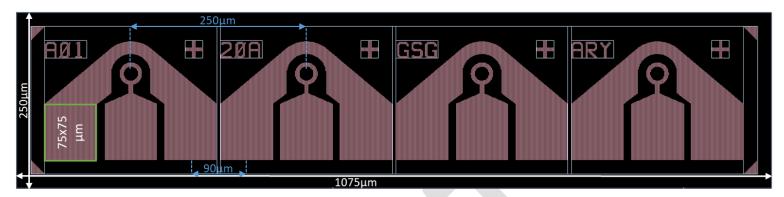
| Parameter | Symbol | Condition | Min. | Тур. | Max. | Unit |
|--------------------------|------------------|---------------------------|------|------|------|------|
| Dark Current | I _D | $V_{bias} = -5V$ | - | 2 | 5 | nA |
| Responsivity | R | λ = 1.31μm | 0.7 | 0.75 | - | A/W |
| | | λ = 1.55μm | 0.65 | 0.7 | - | A/W |
| Forward Voltage | V _{FWD} | I = 1.0mA | - | 0.6 | 0.8 | V |
| Reverse Breakdown | V_{BR} | I _D = 1.0μA | ı | -35 | -45 | V |
| Capacitance | С | $V_{\text{bias}} = -2.5V$ | 85 | 95 | 110 | fF |
| 3dB-Cut-Off Frequency | Fc | V _{bias} = -2.5V | - | 16 | - | GHz |
| ESD rating | V _{ESD} | НВМ | 500 | - | - | V |
| Operating Temperature | T _{OP} | T _{room} = 25°C | -40 | - | +85 | °C |

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Chip layout:



20μm window device with Ground-Signal-Ground (GSG) layout

Device dimensions:

| Parameter | Min. | Тур. | Max. | Unit |
|-------------------------|----------|----------|----------|------|
| Optical window diameter | 19 | 20 | 21 | μm |
| Die Size | 1060x240 | 1070x250 | 1080x260 | μm² |
| Device Pitch | 248 | 250 | 248 | μm |
| Pad Size (Anode) | 73x73 | 75x75 | 77x77 | μm² |
| Pad Size (Cathode) | 73x73 | 75x75 | 77x77 | μm² |
| Die thickness | 140 | 150 | 160 | μm |

^{*}Custom layout dimensions and die thickness are also available.

Revision history:

| Date | Revision | Comment |
|------------|----------|---|
| 22/02/2018 | 1.0 | Initial release |
| 01/06/2018 | 2.0 | Changed cut off frequency |
| 26/11/2018 | 3.0 | Changed cut off (removed 5v) |
| 30/01/2019 | 4.0 | Changed minimum temp. from -25C to -40C |

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